

4A, 50V - 1000V Standard Bridge Rectifier

FEATURES

- AEC-Q101 qualified available
- Ideal for printed circuit board
- High case dielectric strength of 1500V_{RMS}
- High surge current capability
- UL Recognized File # E-326243
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

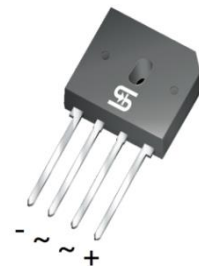
APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application

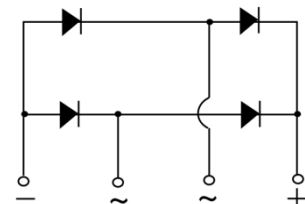
MECHANICAL DATA

- Case: GBU
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Polarity: As marked
- Weight: 4.00g (approximately)

KEY PARAMETERS		
PARAMETER	VALUE	UNIT
I_F	4	A
V_{RRM}	50 - 1000	V
I_{FSM}	150	A
$T_{J\ MAX}$	150	°C
Package	GBU	
Configuration	Quad	



GBU



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)									
PARAMETER	SYMBOL	GBU 401	GBU 402	GBU 403	GBU 404	GBU 405	GBU 406	GBU 407	UNIT
Marking code on the device		GBU 401	GBU 402	GBU 403	GBU 404	GBU 405	GBU 406	GBU 407	
Repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Forward current	I_F	4							A
Surge peak forward current, 8.3ms single half sine-wave superimposed on rated load	$T_J = 25^\circ\text{C}$	150							A
	$T_J = 125^\circ\text{C}$	80							A
Surge peak forward current, 1.0ms single half sine-wave superimposed on rated load	$T_J = 25^\circ\text{C}$	280							A
	$T_J = 125^\circ\text{C}$	260							A

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)									
PARAMETER	SYMBOL	GBU 401	GBU 402	GBU 403	GBU 404	GBU 405	GBU 406	GBU 407	UNIT
Rating for fusing ($t < 8.3\text{ms}$)	I^2t	93							A^2s
Junction temperature	T_J	- 55 to +150							$^\circ\text{C}$
Storage temperature	T_{STG}	- 55 to +150							$^\circ\text{C}$

THERMAL PERFORMANCE			
PARAMETER	SYMBOL	TYP	UNIT
Junction-to-ambient thermal resistance	$R_{\theta\text{JA}}$	20	$^\circ\text{C}/\text{W}$
Junction-to-case thermal resistance	$R_{\theta\text{JC}}$	4	$^\circ\text{C}/\text{W}$

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ\text{C}$ unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	TYP	MAX	UNIT
Forward voltage per diode ⁽¹⁾	$I_F = 2\text{A}, T_J = 25^\circ\text{C}$	V_F	-	1.0	V
	$I_F = 4\text{A}, T_J = 25^\circ\text{C}$		-	1.1	V
Reverse current @ rated V_R per diode ⁽²⁾	$T_J = 25^\circ\text{C}$	I_R	-	5	μA
	$T_J = 125^\circ\text{C}$		-	500	μA
Junction capacitance per diode	1MHz, $V_R = 4.0\text{V}$	C_J	100	-	pF
			45	-	pF

Notes:

1. Pulse test with $PW = 0.3\text{ms}$
2. Pulse test with $PW = 30\text{ms}$

ORDERING INFORMATION		
ORDERING CODE ⁽¹⁾⁽²⁾	PACKAGE	PACKING
GBU40x	GBU	20 / Tube
GBU40xH	GBU	20 / Tube

Notes:

1. "x" defines voltage from 50V(GBU401) to 1000V(GBU407)
2. "H" means AEC-Q101 qualified

CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig.1 Forward Current Derating Curve

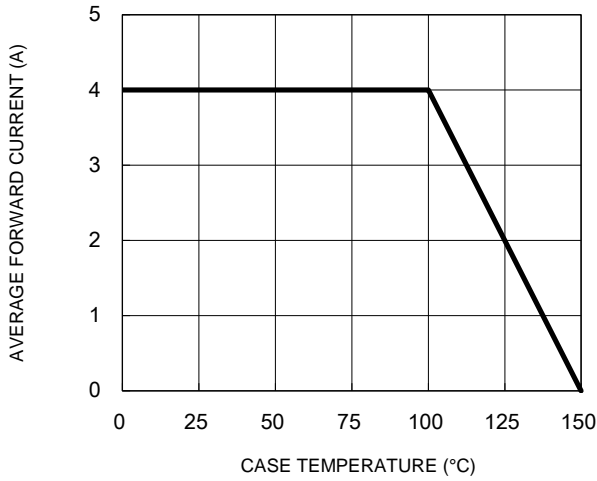


Fig.2 Typical Junction Capacitance

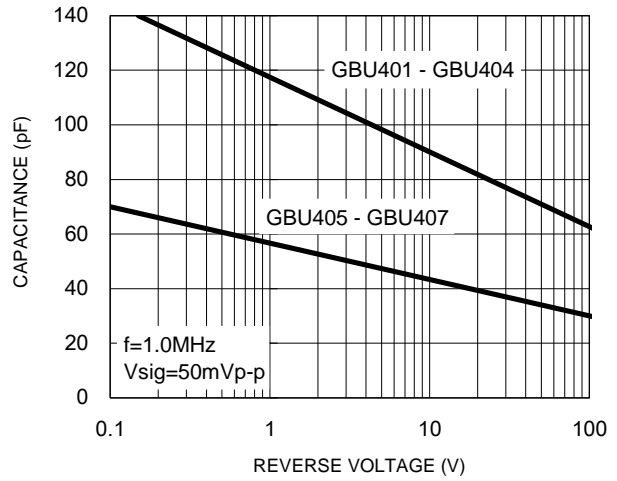


Fig.3 Typical Reverse Characteristics

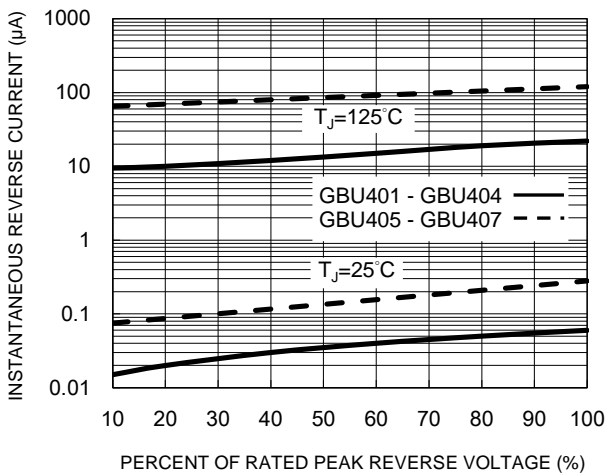


Fig.4 Typical Forward Characteristics

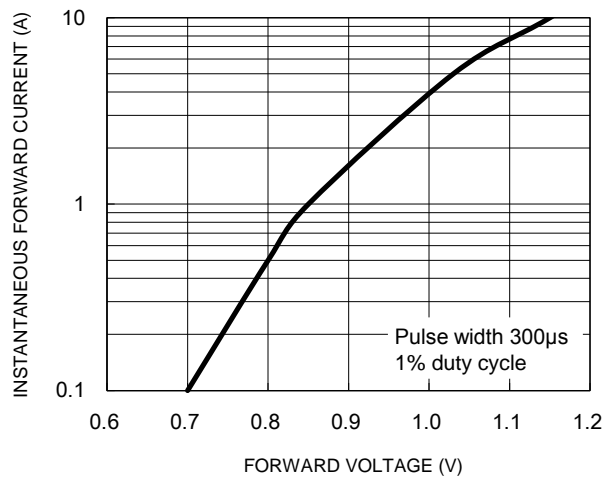
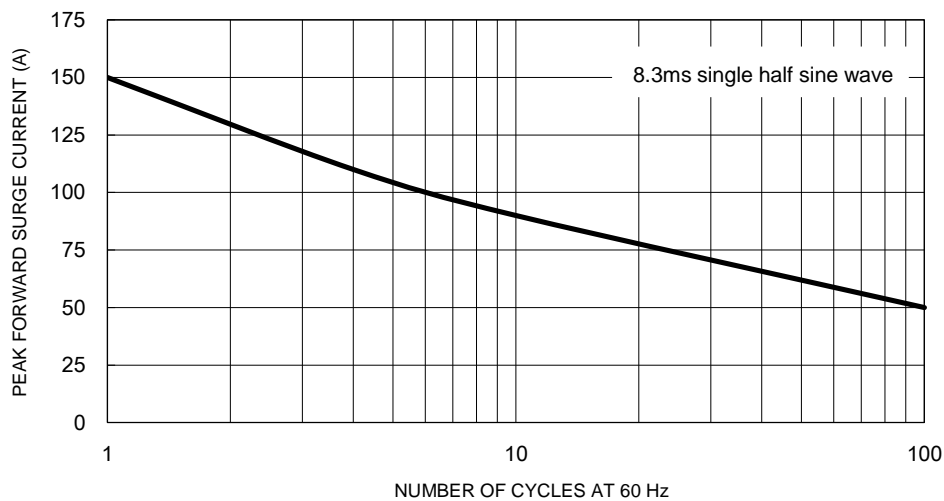
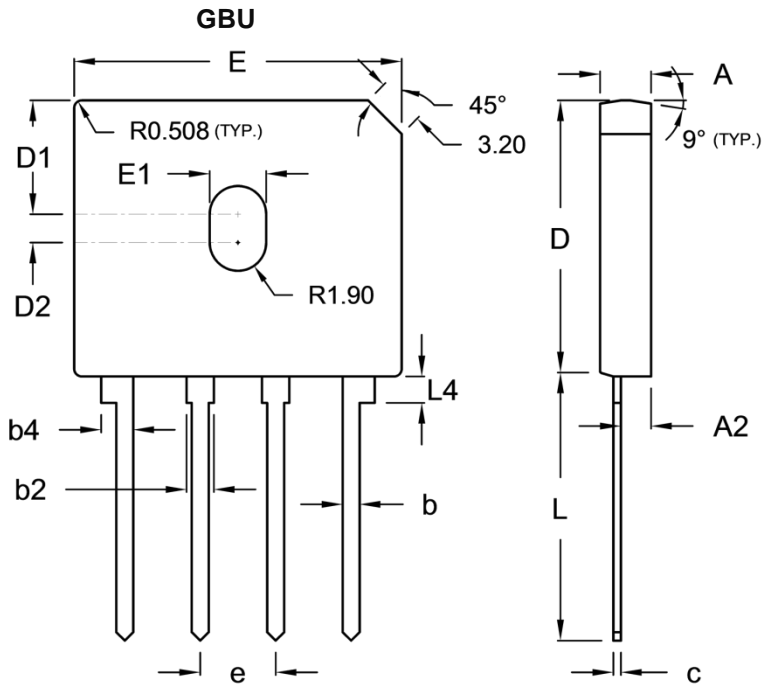


Fig.5 Maximum Non-Repetitive Forward Surge Current



PACKAGE OUTLINE DIMENSIONS



DIM.	Unit (mm)		Unit (inch)	
	Min.	Max.	Min.	Max.
A	3.30	3.56	0.130	0.140
A2	1.90	2.16	0.075	0.085
b	1.02	1.27	0.040	0.050
b2	1.65	2.03	0.065	0.080
b4	2.16	2.54	0.085	0.100
c	0.46	0.56	0.018	0.022
D	18.30	18.80	0.720	0.740
D1	7.40	7.90	0.291	0.311
D2	1.65	2.16	0.065	0.085
E	21.80	22.30	0.858	0.878
E1	3.50	4.10	0.138	0.161
e	4.83	5.33	0.190	0.210
L	17.50	18.00	0.689	0.709
L4	1.52	2.03	0.060	0.080

MARKING DIAGRAM



- P/N = Marking Code
- G = Green Compound
- YWW = Date Code
- F = Factory Code